# Kinetic Study on the Doping Level of ABPBI Membrane

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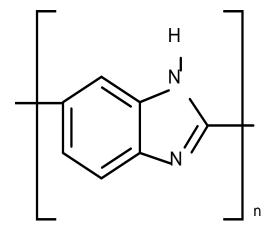
# **Outline**

- > ABPBI membrane
- > Doping process
- Doping level
- Rate law
- Activation energy



# **ABPBI** membrane

ABPBI: poly(2,5-benzimidazole)



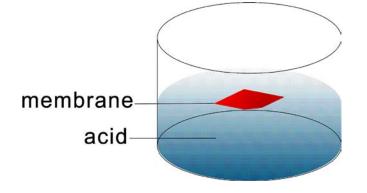
# Current membrane: cross-linked ABPBI polymer exact structure Fuma-Tech (Germany) confidential



# **Doping process**

- Membrane is heated in an open acid bath
- Acid: 85 wt.% phosphoric acid
- Drying surface with tissues

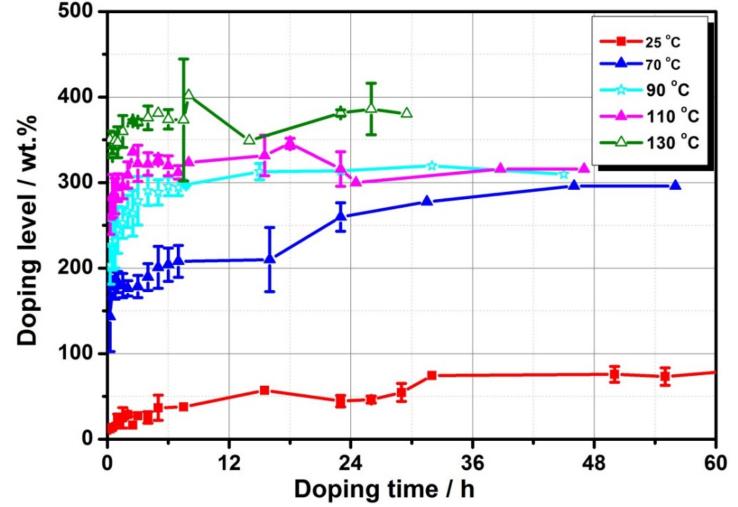
acid doping level = 
$$\frac{W_a}{W_m} \times 100 \%$$



W<sub>m</sub> / g: weight of membrane
W<sub>a</sub> / g: weight of acid in doped membrane



# **Doping level**



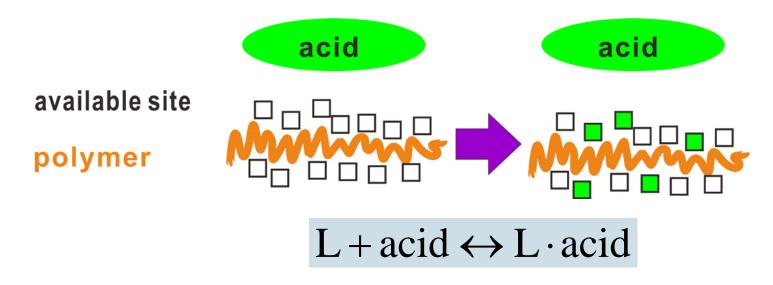
≻ Higher doping temperature ⇒ faster to equilibrium, higher doping level
> At 130 °C, membrane dissolved more and more after 12 h.



# Available sites for adsorption

Assumptions for doping membrane:

- The doping process: an adsorption process.
- The real reaction between acid and polymer: not regarded.
- > Each acid molecule: at a specific volume close to the polymer chain.
- The specific volume: available site, L.

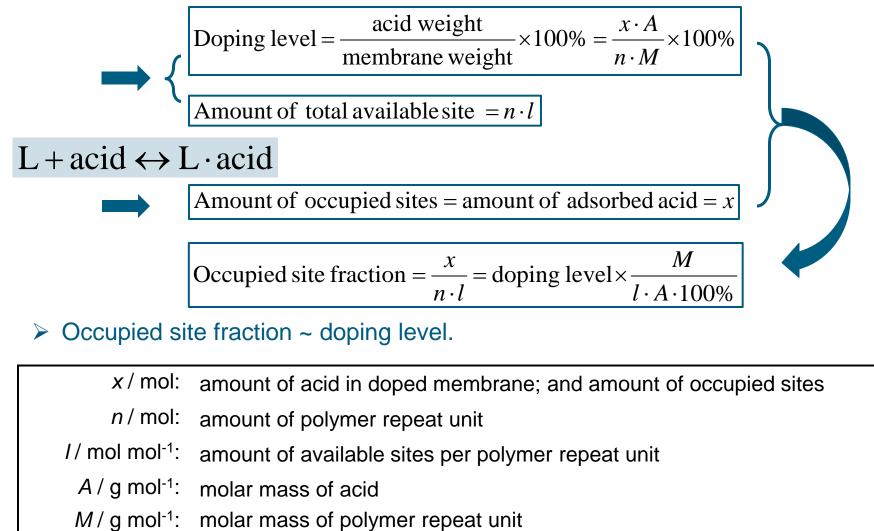


- Reaction: acid & available sites
- Amount of available sites: single digit for each polymer repeat unit constant at a certain temperature



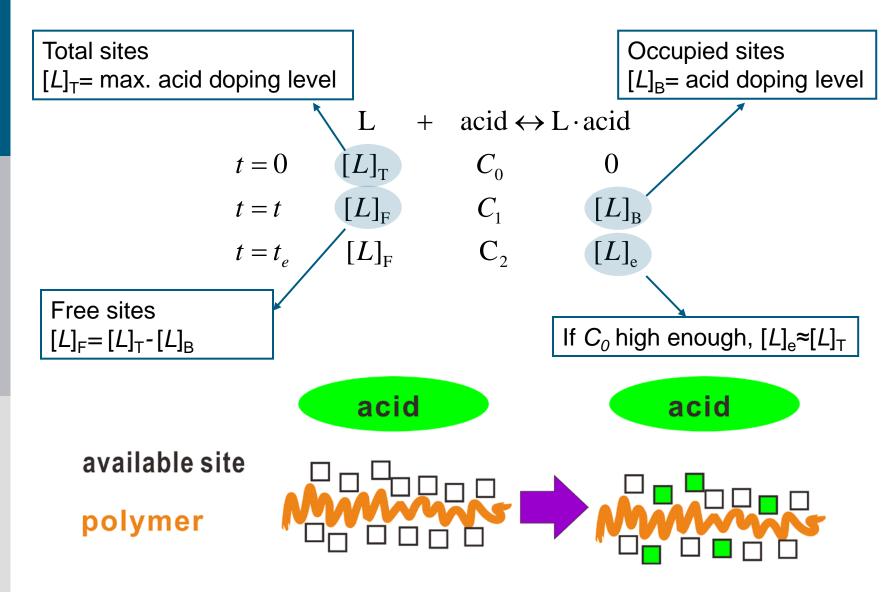
# **Occupied site fraction**

#### Supposing membrane contains *n* repeat unit





# **Adsorption rate**



#### **Reaction rate law**



- Pseudo-first-order reaction rate law
- Pseudo-second-order reaction rate law

Y.S. Ho, Process Biochemistry 34 (1999) 451-465

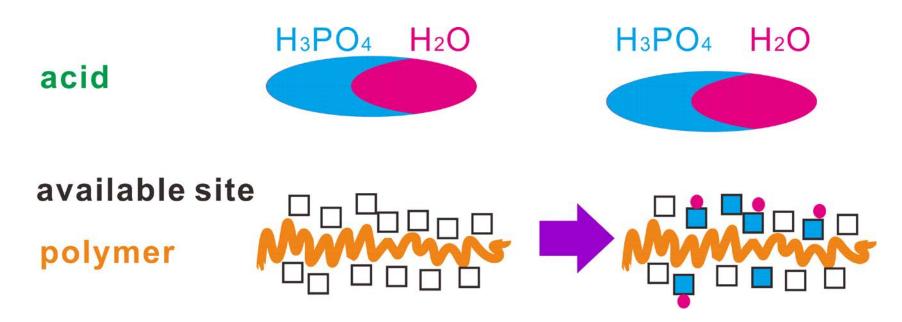
# **Pseudo-first-order reaction rate law**



Assumptions:

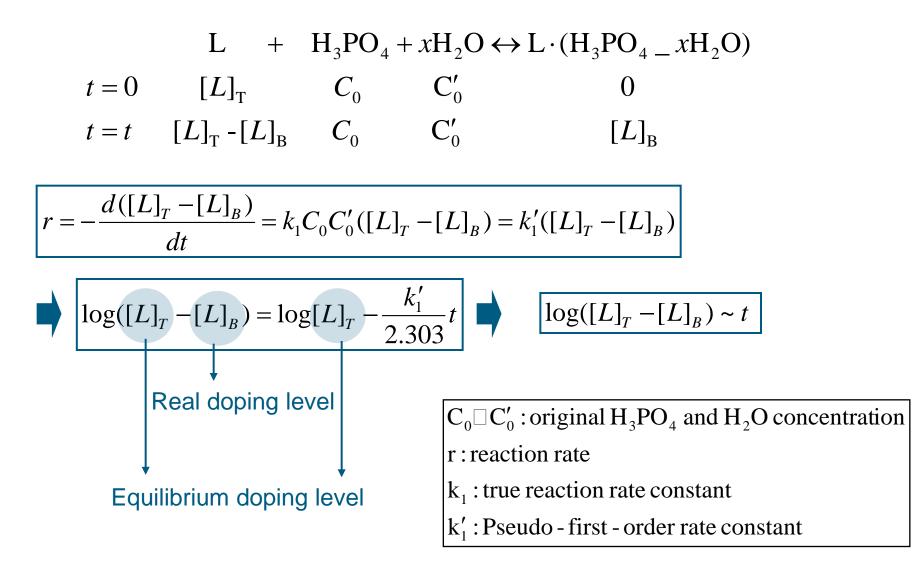
- > Acid concentration in the acid bath does not change during doping process.
- > Occupation of  $H_2O$  on the available sites is negligible.

$$L + H_3PO_4 + xH_2O \leftrightarrow L \cdot (H_3PO_4 \cdot xH_2O)$$





#### **Pseudo-first-order reaction rate law**





## **Pseudo-first-order reaction rate law**

2.5 2.0 % <b>1</b> ,5 ( <sup>a</sup> - <sup>1</sup> )60 1.0 0.5		■ 25 °C ★ 70 °C ★ 90 °C	
Doping temperature / °C	Experimental equilibrium doping level / wt.%	Calculated equilibrium doping level / wt.%	R <sup>2</sup>
25	163	143.1	0.95399
70	296	130.1	0.72469
90	320	56.0	0.42258
110	354	49.3	0.10872
130	349	22.7	-0.04758

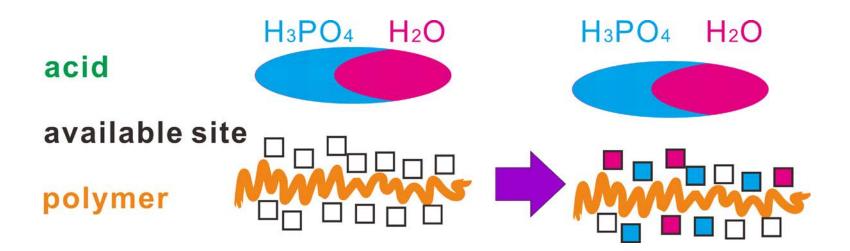
Pseudo-first-order model: only for doping at room temperature.

# **Pseudo-second-order reaction rate law**



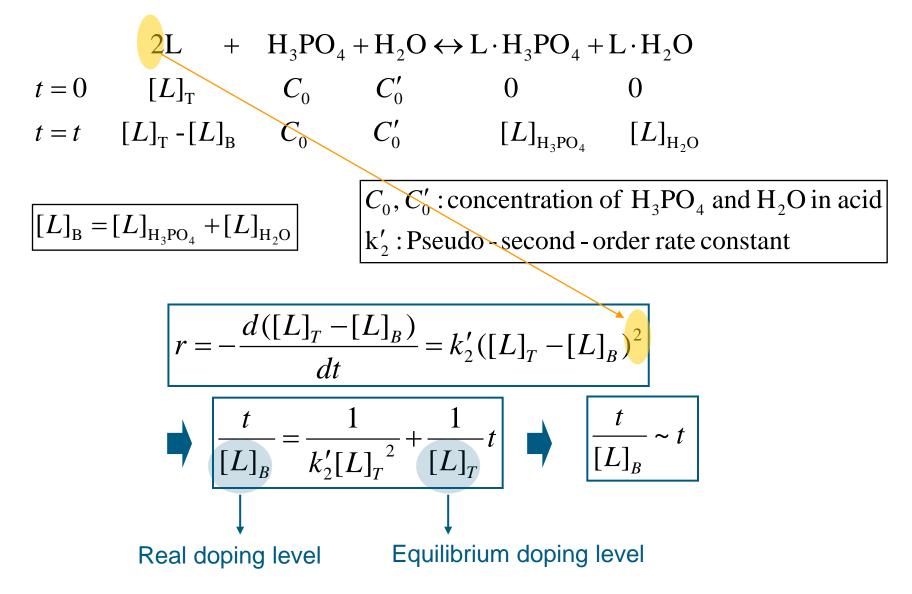
- > Assumption:
- > Acid concentration in the acid bath remains stable during doping process.
- ➢ Both H3PO4 and H2O are able to occupy available sites.

$$2L + H_3PO_4 + H_2O \leftrightarrow L \cdot H_3PO_4 + L \cdot H_2O$$



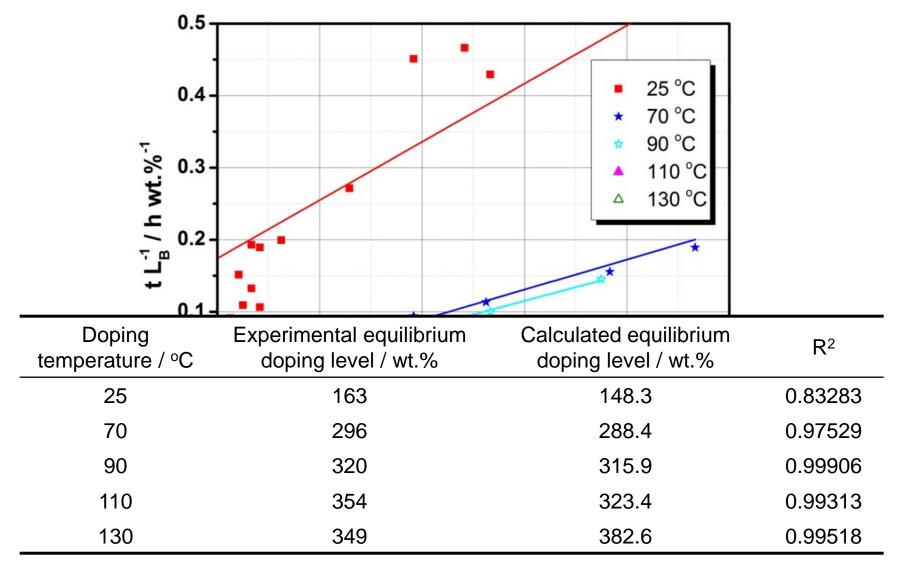


#### **Pseudo-second-order reaction rate law**





#### **Pseudo-second-order reaction rate law**

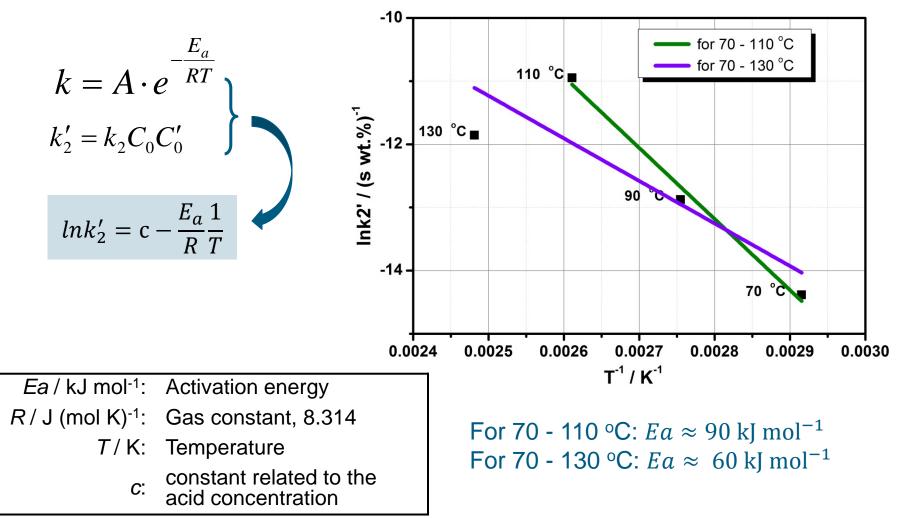


The Pseudo-second-order model: for doping process from 70 to 130 °C



# **Arrhenius Equation**

#### Based on pseudo-second-order reaction rate law

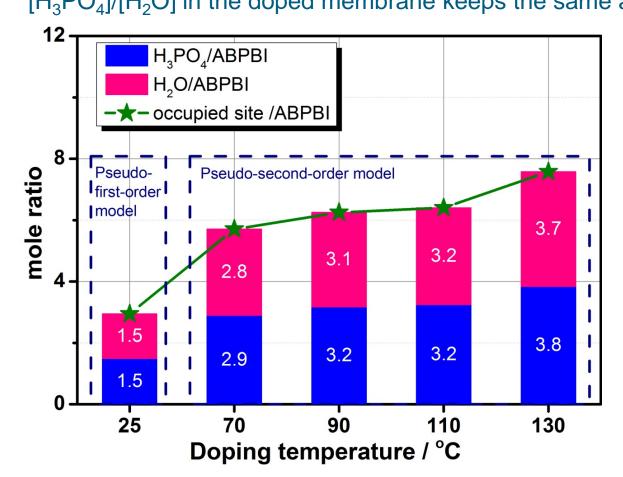




# Amount of available sites

#### In 85 wt.% H3PO4 solution, $[H_3PO_4]/[H_2O] \approx 1$

Supposing:  $[H_3PO_4]/[H_2O]$  in the acid bath keeps stable during the doping process.  $[H_3PO_4]/[H_2O]$  in the doped membrane keeps the same as acid bath.



\* At 130 °C, the membrane was dissolved in a short time. The value is not reliable completely. Institute of Energy and Climate Research IEK-3: Electrochemical Process Engineering



# Conclusion

# > The rate law of doping process:

at room temperature: fitted with the pseudo-first-order reaction rate law; at 70 ~ 130 °C: fitted with the pseudo-second-order reaction rate law.

> The activation energy of doping from 70 to 130 °C is about 90 kJ mol<sup>-1</sup>.



# Thank you for your attention!

